33.3 ± 0.5

Unit: mm

TOSHIBA GTR Module Silicon N Channel IGBT

MG50J1ZS40

High Power Switching Applications Motor Control Applications

• High input impedance

• High speed : $t_f = 0.35 \mu s \text{ (max)}$

 $t_{rr} = 0.15 \mu s \text{ (max)}$

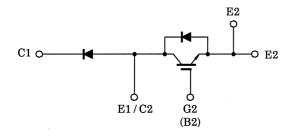
• Low saturation voltage

: VCE(sat) = 3.5V (max)

• Enhancement-mode

• The electrodes are isolated from case.

Equivalent Circuit



3-M5 E2 2-FAST-ON-TAB #110 2-\$\phi 5.6\pm 0.3 2-\$\phi 5.6\pm 0.3

2-94D2A

TOSHIBA Weight: 202g

JEDEC JEITA 91±0.5

Maximum Ratings (Ta = 25°C)

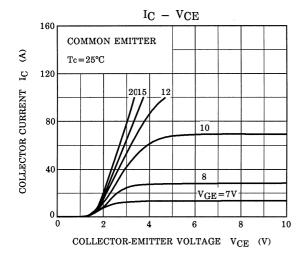
Characteristics		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	600	V	
Gate-emitter voltage		V _{GES}	±20	V	
Reverse voltage		V _R	600	V	
Collector current	DC	I _C	50	Α	
	1ms	I _{CP}	100		
Forward current	DC	lF	50		
	1ms	I _{FM}	100	А	
Collector power dissipation (Tc = 25°C)		PC	250	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-40 ~ 125	°C	
Isolation voltage		V _{Isol}	2500 (AC, 1 minute)	٧	
Screw torque (Terminal / mounting)		_	3/3	N·m	

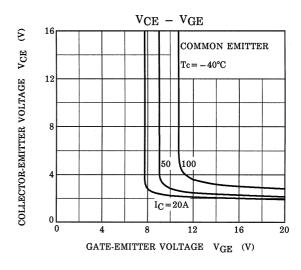
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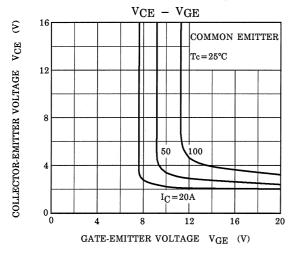
Electrical Characteristics (Ta = 25°C)

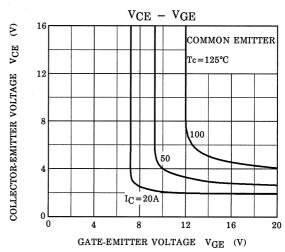
Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	V _{GE} = ±20V, V _{CE} = 0	_	_	±500	nA
Collector cut-off current		I _{CES}	V _{CE} = 600V, V _{GE} = 0	_	_	1.0	mA
Collector-emitter breakdown voltage		V _{(BR)CES}	I _C = 10mA, V _{GE} = 0	600	_	_	٧
Gate-emitter cut-off voltage		V _{GE} (off)	I _C = 50mA, V _{CE} = 5V	3.0	_	6.0	V
Collector-emitter saturation voltage		V _{CE} (sat)	I _C = 50A, V _{GE} = 15V	_	2.7	3.5	V
Input capacitance		C _{ies}	V _{CE} = 10V, V _{GE} = 0f = 1MHz	_	4000	_	pF
Switching time	Rise time	t _r	_ _	_	0.30	0.60	- µs
	Turn-on time	t _{on}	15V 51Ω \$ C	_	0.40	0.80	
	Fall time	t _f	\bigcup_{-15}°	-	0.18	0.35	
	Turn-off time	t _{off}	300V	-	0.60	1.00	
Reverse current		I _R	V _R = 600V		_	1.0	mA
Forward voltage		V _F	I _F = 50A, V _{GE} = 0		1.7	2.5	V
Reverse recovery time		t _{rr}	I _F = 50 A, V _{GE} = -10 V, di / dt = 100 A / μs	_	0.08	0.15	μs
Thermal resistance		R _{th (j-c)}	Transistor	0.5		0.50	°C/W
			Diode	_	_	1.00] 0/ W

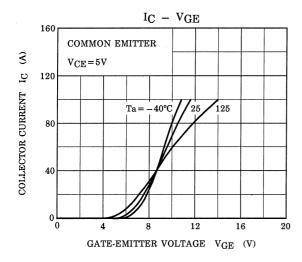
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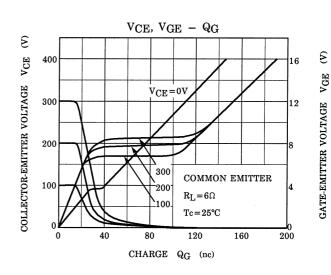




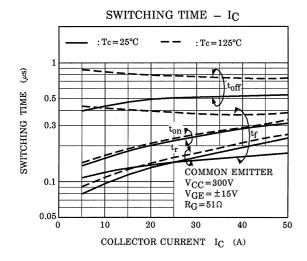


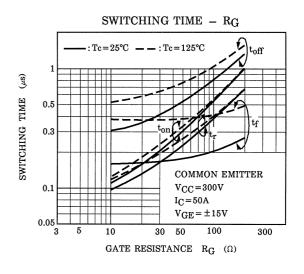


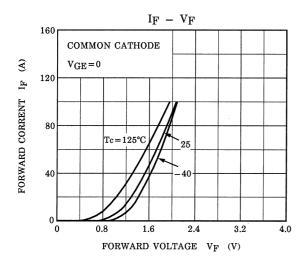


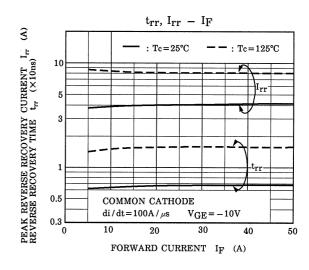


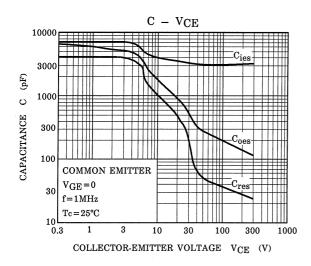
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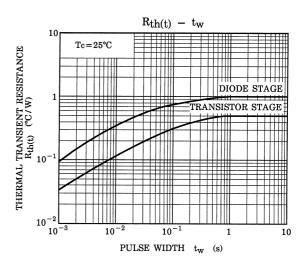


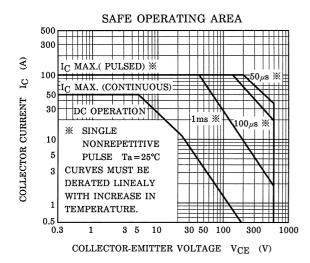


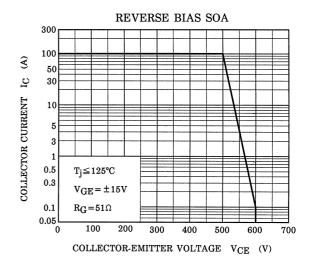












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